

Vishay Telefunken



Silicon PIN Photodiode

Description

BPW46L is a high speed and high sensitive PIN photodiode in a flat side view plastic package. Due to its waterclear epoxy the device is sensitive to visible and infrared radiation.

The large active area combined with a flat case gives a high sensitivity at a wide viewing angle.

Features

- Long lead package (33,2 mm)
- Large radiant sensitive area (A=7.5 mm²)
- Wide angle of half sensitivity $\phi = \pm 65^{\circ}$
- High photo sensitivity
- Fast response times
- Small junction capacitance
- Clear plastic case
- Suitable for visible and near infrared radiation

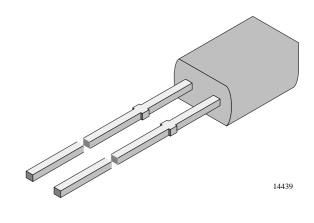
Applications

High speed photo detector

Absolute Maximum Ratings

 $T_{amb} = 25^{\circ}C$

Parameter	Test Conditions	Symbol	Value	Unit
Reverse Voltage		V _R	60	V
Power Dissipation	$T_{amb} \leq 25 \ ^{\circ}C$	PV	215	mW
Junction Temperature		Т _і	100	°C
Storage Temperature Range		T _{stg}	-55+100	°C
Soldering Temperature	t ≦ 5 s	T _{sd}	260	°C
Thermal Resistance Junction/Ambient		R _{thJA}	350	K/W



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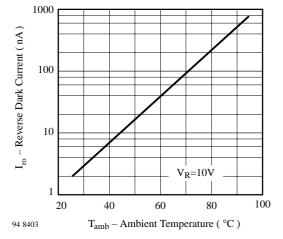


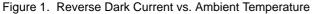
Basic Characteristics

Iamb	=	25°	С
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Parameter	Test Conditions	Symbol	Min	Тур	Max	Unit
Breakdown Voltage	I _R = 100 μA, E = 0	V _(BR)	60			V
Reverse Dark Current	$V_{R} = 10 V, E = 0$	I _{ro}		2	30	nA
Diode Capacitance	$V_{R} = 0 V, f = 1 MHz, E = 0$	CD		70		pF
	V _R = 3 V, f = 1 MHz, E = 0	CD		25	40	pF
Open Circuit Voltage	$E_e = 1 \text{ mW/cm}^2$, $\lambda = 950 \text{ nm}$	Vo		350		mV
Temp. Coefficient of Vo	$E_e = 1 \text{ mW/cm}^2$, $\lambda = 950 \text{ nm}$	TK _{Vo}		-2.6		mV/K
Short Circuit Current	$E_A = 1 \text{ klx}$	l _k		70		μΑ
	$E_e = 1 \text{ mW/cm}^2$, $\lambda = 950 \text{ nm}$	l _k		47		μA
Temp. Coefficient of Ik	$E_e = 1 \text{ mW/cm}^2$, $\lambda = 950 \text{ nm}$	ΤΚ _{lk}		0.1		%/K
Reverse Light Current	$E_A = 1 \text{ klx}, V_R = 5 \text{ V}$	I _{ra}		75		μΑ
	$E_e = 1 \text{ mW/cm}^2$, $\lambda = 950 \text{ nm}$, $V_R = 5 \text{ V}$	I _{ra}	40	50		μΑ
Angle of Half Sensitivity		φ		±65		deg
Wavelength of Peak Sensitivity		λρ		900		nm
Range of Spectral Bandwidth		λ _{0.5}		6001050		nm
Noise Equivalent Power	$V_{R} = 10 V, \lambda = 950 nm$	NEP		4x10 ⁻¹⁴		W/√ Hz
Rise Time	$V_R = 10$ V, $R_L = 1k$ Ω, $\lambda = 820$ nm	t _r		100		ns
Fall Time	$V_R = 10$ V, $R_L = 1k$ Ω, $\lambda = 820$ nm	t _f		100		ns

Typical Characteristics ($T_{amb} = 25^{\circ}C$ unless otherwise specified)





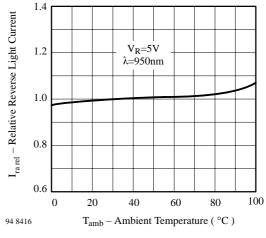


Figure 2. Relative Reverse Light Current vs. Ambient Temperature



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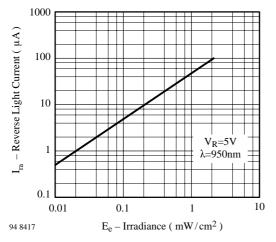


Figure 3. Reverse Light Current vs. Irradiance

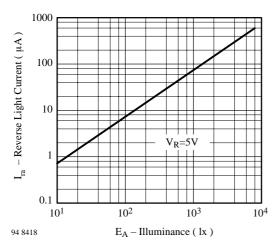


Figure 4. Reverse Light Current vs. Illuminance

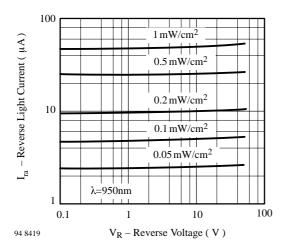


Figure 5. Reverse Light Current vs. Reverse Voltage

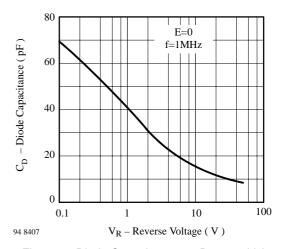
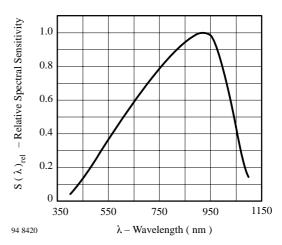
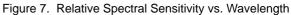


Figure 6. Diode Capacitance vs. Reverse Voltage





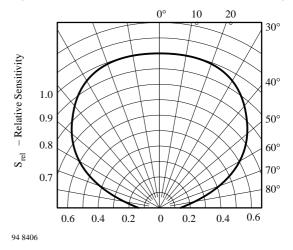


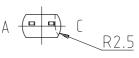
Figure 8. Relative Radiant Sensitivity vs. Angular Displacement

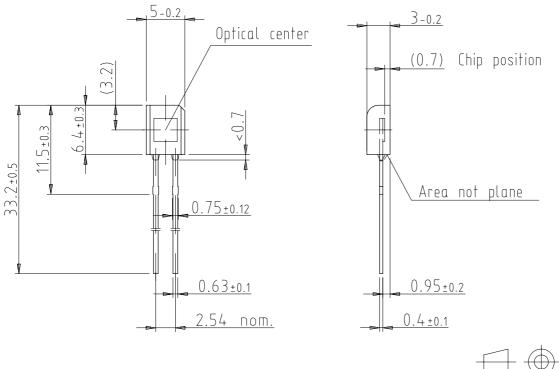
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Dimensions in mm





14437



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Ozone Depleting Substances Policy Statement

It is the policy of Vishay Semiconductor GmbH to

- 1. Meet all present and future national and international statutory requirements.
- 2. Regularly and continuously improve the performance of our products, processes, distribution and operating systems with respect to their impact on the health and safety of our employees and the public, as well as their impact on the environment.

It is particular concern to control or eliminate releases of those substances into the atmosphere which are known as ozone depleting substances (ODSs).

The Montreal Protocol (1987) and its London Amendments (1990) intend to severely restrict the use of ODSs and forbid their use within the next ten years. Various national and international initiatives are pressing for an earlier ban on these substances.

Vishay Semiconductor GmbH has been able to use its policy of continuous improvements to eliminate the use of ODSs listed in the following documents.

- 1. Annex A, B and list of transitional substances of the Montreal Protocol and the London Amendments respectively
- 2. Class I and II ozone depleting substances in the Clean Air Act Amendments of 1990 by the Environmental Protection Agency (EPA) in the USA
- 3. Council Decision 88/540/EEC and 91/690/EEC Annex A, B and C (transitional substances) respectively.

Vishay Semiconductor GmbH can certify that our semiconductors are not manufactured with ozone depleting substances and do not contain such substances.

We reserve the right to make changes to improve technical design and may do so without further notice.

Parameters can vary in different applications. All operating parameters must be validated for each customer application by the customer. Should the buyer use Vishay-Telefunken products for any unintended or unauthorized application, the buyer shall indemnify Vishay-Telefunken against all claims, costs, damages, and expenses, arising out of, directly or indirectly, any claim of personal damage, injury or death associated with such unintended or unauthorized use.

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